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 勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-54151736
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

Low Voltage Reference

Features

- Low Bias Current - 50 μ A Min
- Low Dynamic Impedance
- Low Reverse Voltage
- Low Cost

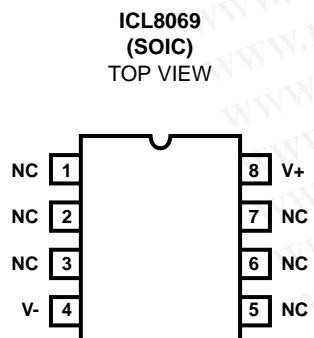
Description

The ICL8069 is a 1.2V temperature compensated voltage reference. It uses the band-gap principle to achieve excellent stability and low noise at reverse currents down to 50 μ A. Applications include analog-to-digital converters, digital-to-analog converters, threshold detectors, and voltage regulators. Its low power consumption makes it especially suitable for battery operated equipment.

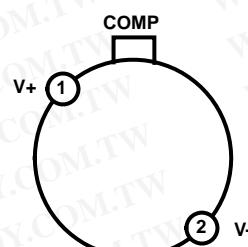
Ordering Information

PART NUMBER	MAXIMUM TEMPCO	TEMPERATURE RANGE	PACKAGE
ICL8069CCZR	0.005%/°C	0°C to +70°C	TO-92
ICL8069CCSQ	0.005%/°C	0°C to +70°C	TO-52
ICL8069DCZR	0.01%/°C	0°C to +70°C	TO-92
ICL8069DCSQ	0.01%/°C	0°C to +70°C	TO-52
ICL8069CCBA	0.005%/°C	0°C to +70°C	8 Lead SOIC
ICL8069DCBA	0.01%/°C	0°C to +70°C	8 Lead SOIC
ICL8069CMSQ	0.005%/°C	-55°C to +125°C	TO-52
ICL8069DMSQ	0.01%/°C	-55°C to +125°C	TO-52

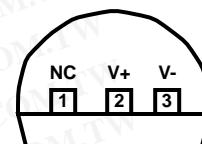
Pinouts



ICL8069
(TO-52)
TOP VIEW

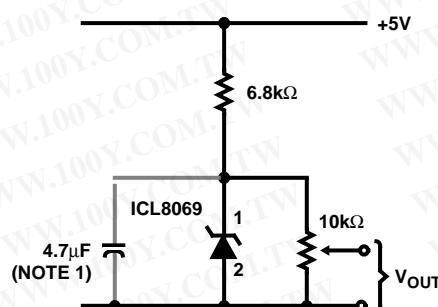


ICL8069
(TO-92)
TOP VIEW

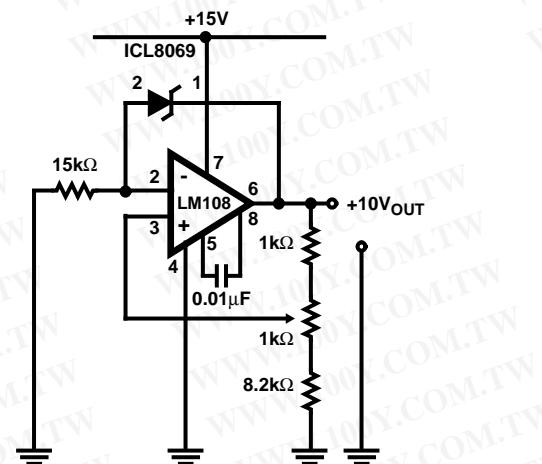


Functional Block Diagrams

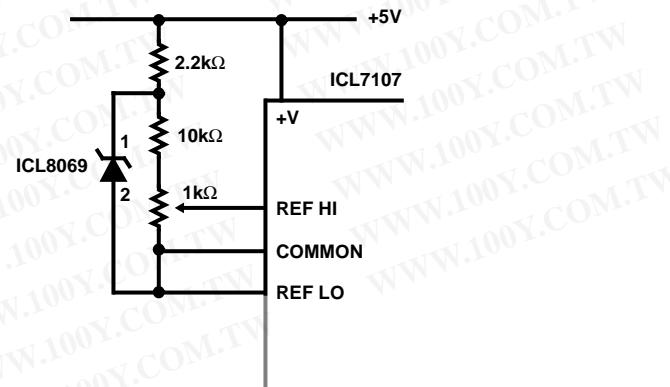
SIMPLE REFERENCE (1.2V OR LESS)



BUFFERED 10V REFERENCE USING A SINGLE SUPPLY



DOUBLE REGULATED 100mV REFERENCE FOR ICL7107 ONE-CHIP DPM CIRCUIT



Specifications ICL8069

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Absolute Maximum Ratings

Reverse Voltage	See Note 2
Forward Current	10mA
Reverse Current	10mA
Storage Temperature	-65°C to +150°C
Lead Temperature (Soldering, 10s)	+300°C
Junction Temperature SOP	+150°C

Thermal Information

Thermal Resistance SOIC Package	θ_{JA} 160°C/W
Operating Temperature ICL8069C	0°C to +70°C
ICL8069M	-55°C to +125°C

Power Dissipation Limited by MAX Forward/Reverse Current

Electrical Specifications $T_A = +25^\circ\text{C}$ Unless Otherwise Specified

PARAMETERS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Reverse Breakdown Voltage	$I_R = 500\mu\text{A}$	1.20	1.23	1.25	V
Reverse Breakdown Voltage Change	$50\mu\text{A} \leq I_R \leq 5\text{mA}$	-	15	20	mV
Reverse Dynamic Impedance	$I_R = 50\mu\text{A}$	-	1	2	Ω
	$I_R = 500\mu\text{A}$	-	1	2	Ω
Forward Voltage Drop	$I_F = 500\mu\text{A}$	-	0.7	1	V
RMS Noise Voltage	$10\text{Hz} \leq F \leq 10\text{kHz}$ $I_R = 500\mu\text{A}$	-	5	-	μV
Long Term Stability	$I_R = 4.75\text{mA}$ $T_A = +25^\circ\text{C}$	-	1	-	ppm/kHR
Breakdown Voltage Temperature Coefficient ICL8069C	$I_R = 500\mu\text{A}$, T_A = Operating Temperature Range (Note 3)	-	-	0.005	%/ $^\circ\text{C}$
ICL8069D		-	-	0.01	%/ $^\circ\text{C}$
Reverse Current Range	1.18V to 1.27V	0.050	-	5	mA

NOTES:

- If circuit strays in excess of 200pF are anticipated, a 4.7 μF shunt capacitor will ensure stability under all operating conditions.
- In normal use, the reverse voltage cannot exceed the reference voltage. However when plugging units into a powered-up test fixture, an instantaneous voltage equal to the compliance of the test circuit will be seen. This should not exceed 20V.
- For the military part, measurements are made at $+25^\circ\text{C}$, -55°C , and $+125^\circ\text{C}$. The unit is then classified as a function of the worst case TC from $+25^\circ\text{C}$ to -55°C , or $+25^\circ\text{C}$ to $+125^\circ\text{C}$.

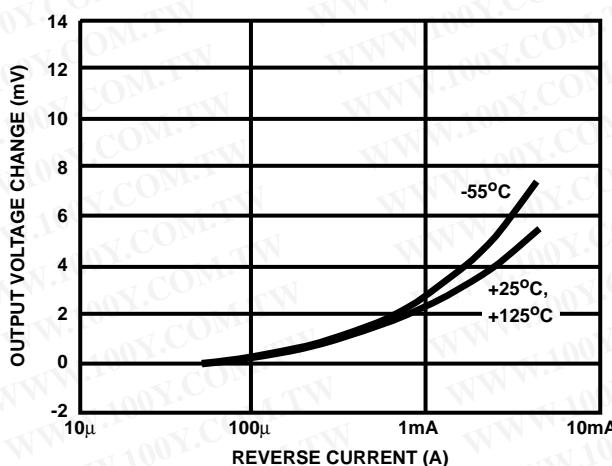
Typical Performance Curves

FIGURE 1. VOLTAGE CHANGE AS A FUNCTION OF REVERSE CURRENT

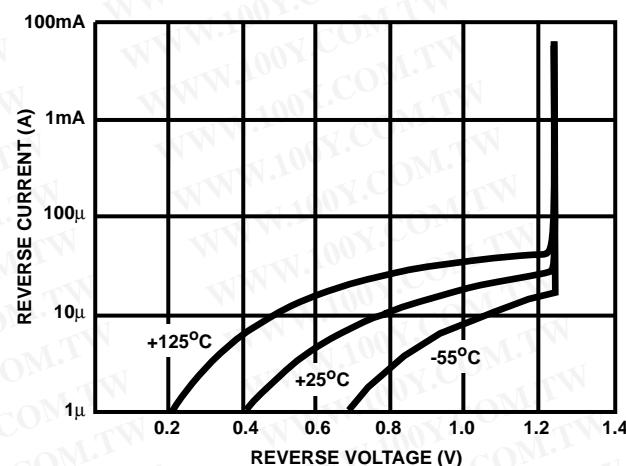


FIGURE 2. REVERSE VOLTAGE AS A FUNCTION OF CURRENT

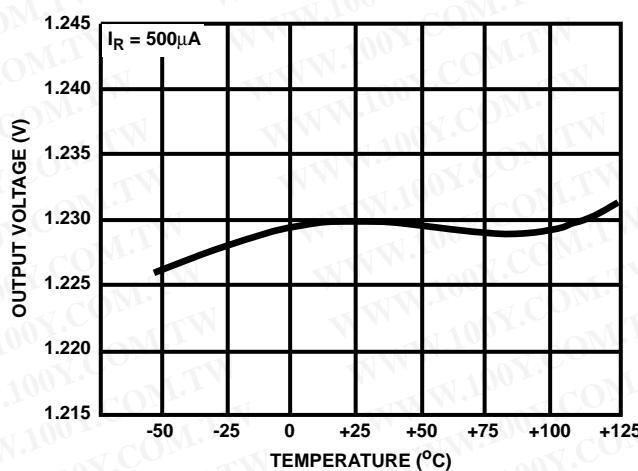


FIGURE 3. REVERSE VOLTAGE AS A FUNCTION OF TEMPERATURE